



PJQ5444

40V N-Channel Enhancement Mode MOSFET

Voltage

40 V

Current

70A

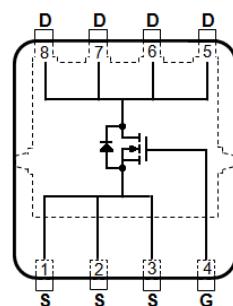
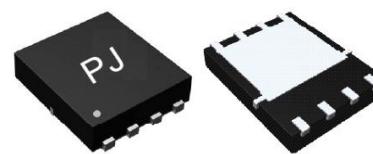
Features

- $R_{DS(ON)}$, $V_{GS}=10V$, $I_D=20A < 6.5m\Omega$
- $R_{DS(ON)}$, $V_{GS}=4.5V$, $I_D=10A < 9m\Omega$
- High switching speed
- Improved dv/dt capability
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0028 ounces, 0.08 grams

DFN5060-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNITS |
|---|---------------------|-----------------|-------|
| Drain-Source Voltage | V_{DS} | 40 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | |
| Continuous Drain Current ^(Note 4) | I_D | 70 | A |
| $T_C=100^\circ C$ | | 44 | |
| Pulsed Drain Current ^(Note 1) | I_{DM} | 280 | |
| Power Dissipation | P_D | 83 | W |
| $T_C=100^\circ C$ | | 33 | |
| Continuous Drain Current ^(Note 4) | I_D | 12.7 | A |
| $T_A=70^\circ C$ | | 10 | |
| Power Dissipation | P_D | 2.0 | W |
| $T_A=70^\circ C$ | | 1.3 | |
| Single Pulse Avalanche Energy ^(Note 6) | E_{AS} | 80 | mJ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55~150 | °C |
| Typical Thermal Resistance ^(Note 4,5) | Junction to Case | $R_{\theta JC}$ | 1.5 |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 |

- Limited only by Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|--------------|--|------|------|-----------|-----------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 40 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 1 | 1.61 | 2.5 | |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=20A$ | - | 5.5 | 6.5 | $m\Omega$ |
| | | $V_{GS}=4.5V, I_D=10A$ | - | 7 | 9 | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=40V, V_{GS}=0V$ | - | - | 1 | μA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | - | - | ± 100 | nA |
| Dynamic (Note 7) | | | | | | |
| Total Gate Charge | Q_g | $V_{DS}=20V, I_D=10A,$ $V_{GS}=4.5V$ (Note 1,2) | - | 17 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 4.9 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 6.4 | - | |
| Input Capacitance | C_{iss} | $V_{DS}=25V, V_{GS}=0V,$ $f=1MHz$ | - | 1759 | - | pF |
| Output Capacitance | C_{oss} | | - | 176 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 126 | - | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}=15V, I_D=1A,$ $V_{GS}=10V, R_G=6\Omega$ (Note 1,2) | - | 11 | - | ns |
| Turn-On Rise Time | t_r | | - | 21 | - | |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 40 | - | |
| Turn-Off Fall Time | t_f | | - | 25 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I_s | --- | - | - | 70 | A |
| Diode Forward Voltage | V_{SD} | $I_s=1A, V_{GS}=0V$ | - | 0.7 | 1 | V |

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ C$. Ratings are based on low frequency and duty cycles to keep initial $T_J = 25^\circ C$.
4. The maximum current rating is package limited.
5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. The test condition is $L=0.1mH, I_{AS}=40A, V_{DD}=25V, V_{GS}=10V$.
7. Guaranteed by design, not subject to production testing.



PJQ5444

TYPICAL CHARACTERISTIC CURVES

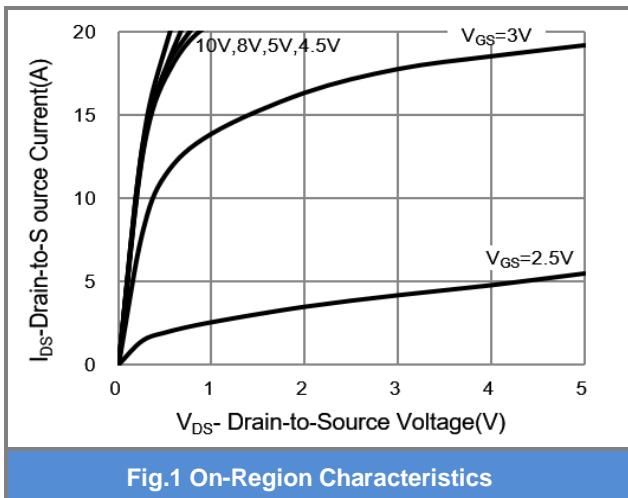


Fig.1 On-Region Characteristics

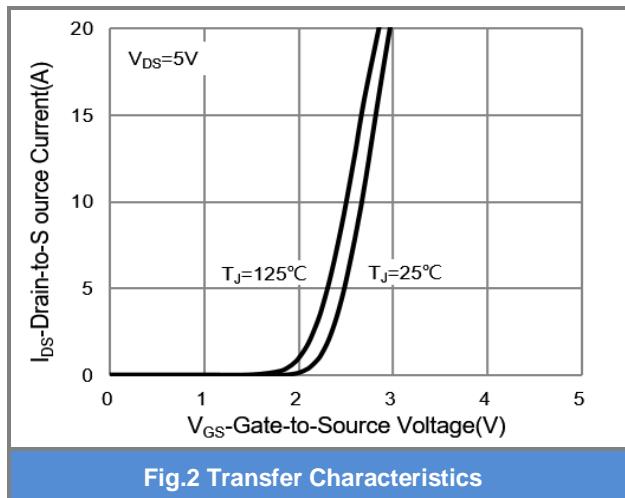


Fig.2 Transfer Characteristics

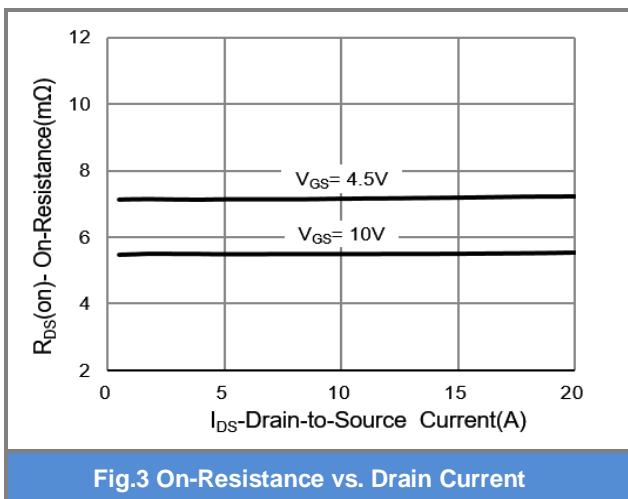


Fig.3 On-Resistance vs. Drain Current

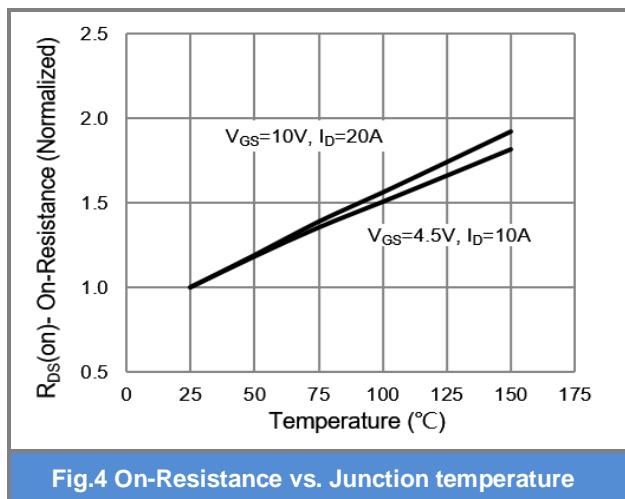


Fig.4 On-Resistance vs. Junction temperature

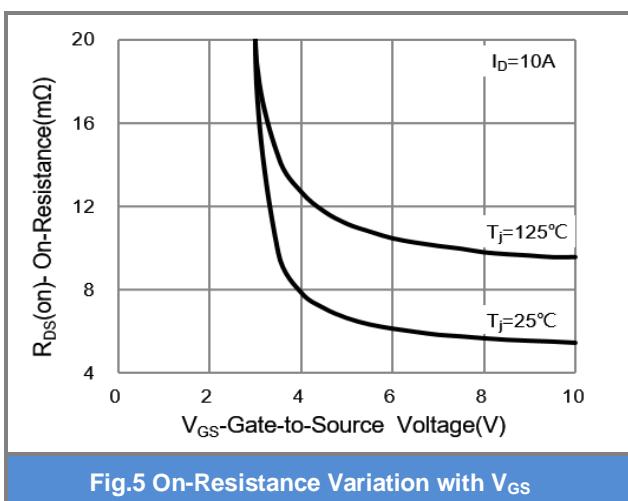


Fig.5 On-Resistance Variation with V_GS

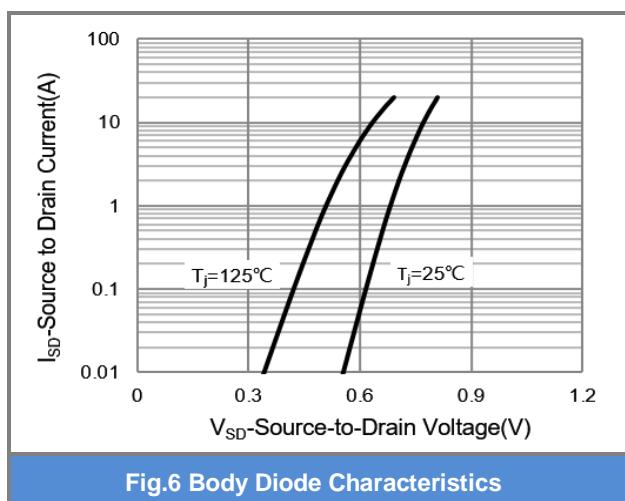


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

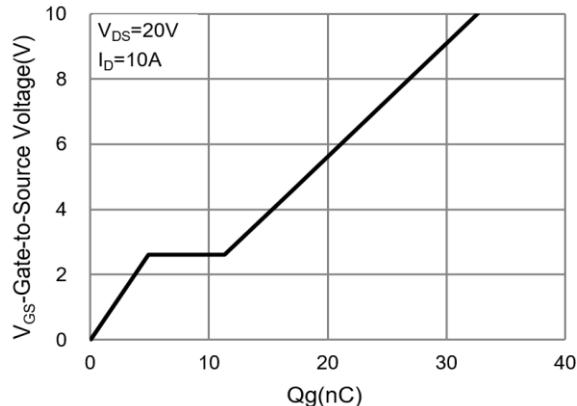


Fig.7 Gate-Charge Characteristics

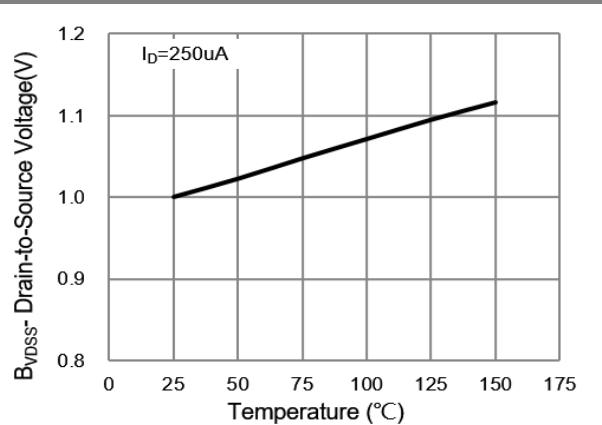


Fig.8 Breakdown Voltage Variation vs. Temperature

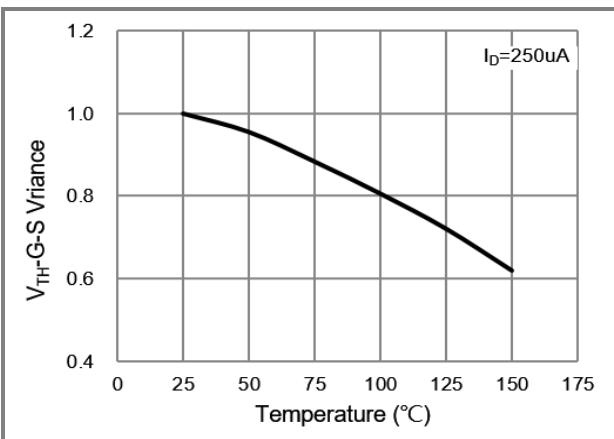


Fig.9 Threshold Voltage Variation with Temperature

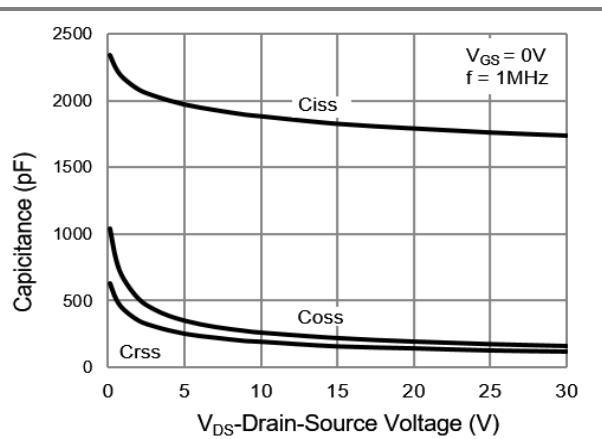


Fig.10 Capacitance vs. Drain-Source Voltage

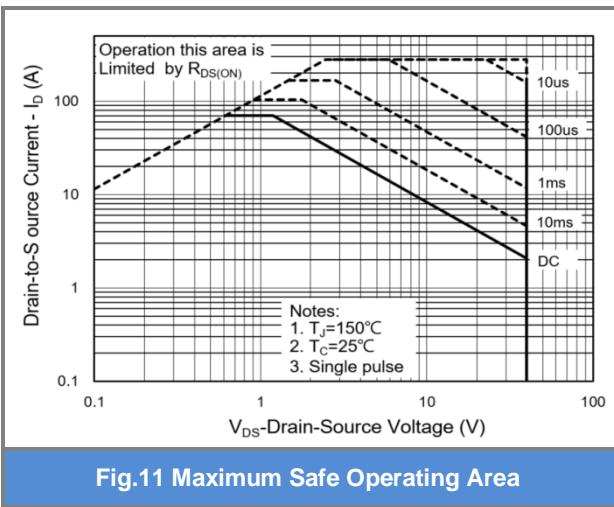


Fig.11 Maximum Safe Operating Area

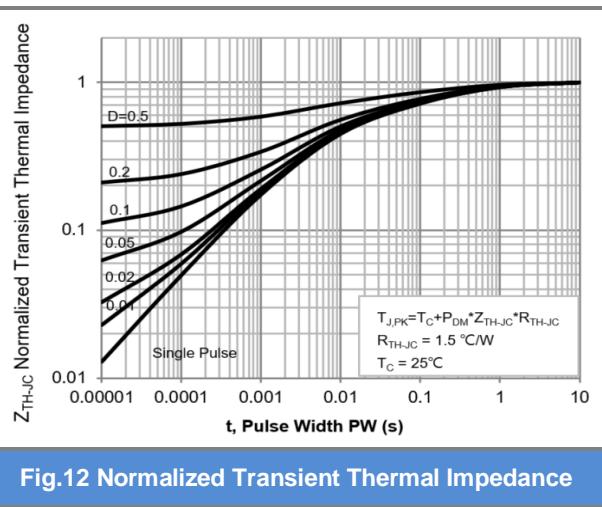


Fig.12 Normalized Transient Thermal Impedance

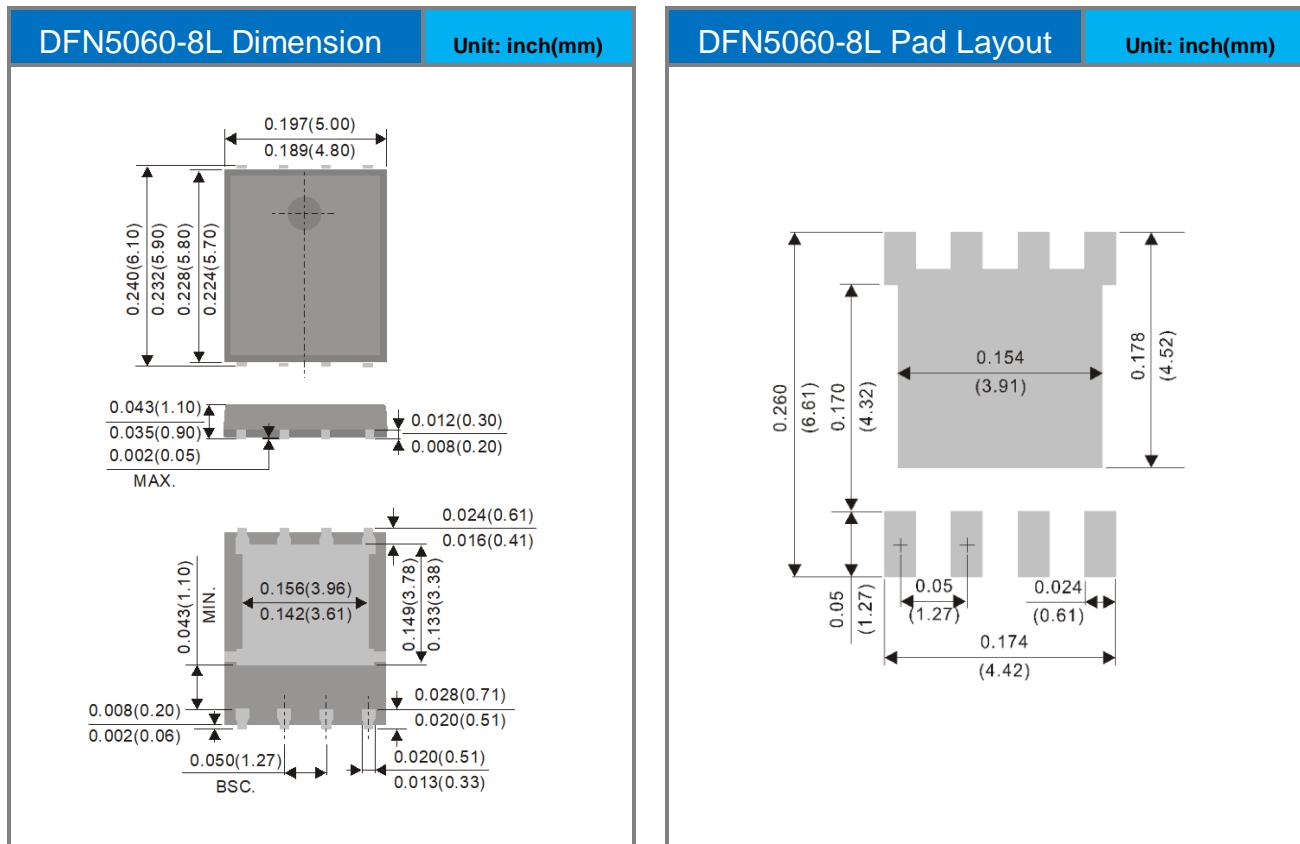


PJQ5444

Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version |
|----------------------|--------------|--------------------|---------|--------------|
| PJQ5444_R2_00001 | DFN5060-8L | 3000pcs / 13" reel | Q5444 | Halogen free |

Packaging Information & Mounting Pad Layout





PJQ5444

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